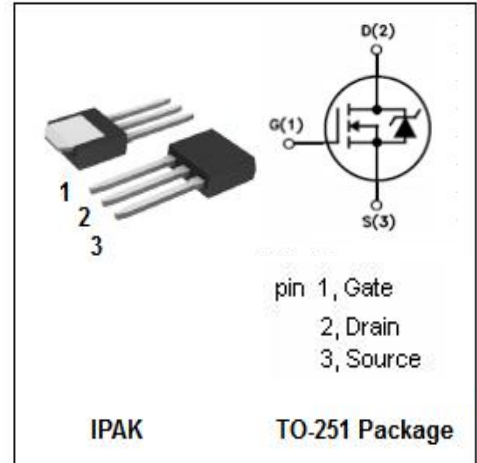


isc N-Channel MOSFET Transistor
IPU80R1K4CE
FEATURES

- Static drain-source on-resistance:
 $R_{DS(on)} \leq 1.4 \Omega$ (@ $V_{GS} = 10V$; $I_D = 2.3A$)
- Advanced trench process technology
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

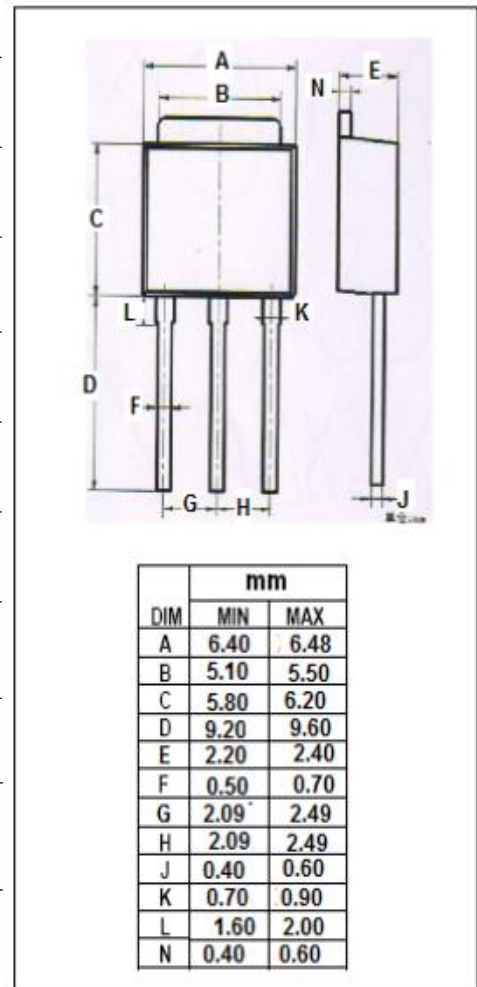
- Fast switching application.


ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	800	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	3.9	A
P_D	Total Dissipation @ $T_c = 25^\circ C$	63	W
T_j	Max. Operating Junction Temperature	-55~150	$^\circ C$
T_{stg}	Storage Temperature	-55~150	$^\circ C$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Channel-to-case thermal resistance	2	$^\circ C/W$



isc N-Channel MOSFET Transistor

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ELECTRICAL CHARACTERISTICS

T_C=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 250uA	800		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D = 0.24mA	2.1	3.9	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 2.3A		1.4	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V; V _{DS} = 0V		± 100	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 800V; V _{GS} = 0V		10	μ A
V _{SD}	Diode forward voltage	I _S = 3.9A, V _{GS} = 0V		1.2	V

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